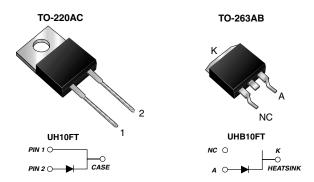




Vishay General Semiconductor

Ultrafast Recovery Rectifier



| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|--------|--|--|--|
| I _{F(AV)} | 10 A | | | |
| V _{RRM} | 300 V | | | |
| I _{FSM} | 180 A | | | |
| t _{rr} | 25 ns | | | |
| V _F | 0.83 V | | | |
| T _J max. | 175 °C | | | |

FEATURES





· Ultrafast recovery times



Soft recovery characteristics

RoHS

Low switching losses, high efficiency

· High forward surge capability

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for consumer.

MECHANICAL DATA

Case: TO-220AC and TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|-----------------------------------|----------------|--|------|--|
| PARAMETER | SYMBOL | UH10FT UHB10FT | | UNIT | |
| Maximum repetitive peak reverse voltage | V_{RRM} | 300 | | V | |
| Maximum average forward rectified current (Fig. 1) | I _{F(AV)} | 10 | | Α | |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load | I _{FSM} | 180 | | А | |
| Operating junction and storage temperature range | T _J , T _{STG} | - 55 to + 175 | | °C | |

UH10FT & UHB10FT

Vishay General Semiconductor



| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|--|---|-----------------|--------------|-------------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Maximum instantaneous forward voltage (1) | I _F = 5.0 A I _F = 5.0 A | T _J = 25 °C T _J = 125 °C | V _F | 0.96 0.77 | - | V |
| | I _F = 10 A I _F = 10 A | T _J = 25 °C T _J = 125 °C | | 1.0 0.83 | 1.2 0.90 | |
| Maximum reverse current (2) | V _R = 300 V | T _J = 25 °C T _J = 125 °C | I _R | 0.5 25 | 5 150 | μΑ |
| Maximum reverse recovery time | I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A | | t _{rr} | 20 | 25 | ns |
| Maximum reverse recovery time | $I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, $ $V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$ | | t _{rr} | 28 | 35 | ns |
| Typical softness factor (tb/ta) | I _F = 10 A, dl/dt = 200 A/μs, V _R = 200 V, T _J = 125 °C | | S | 0.36 | - | - |
| Typical reverse recovery current | | | I _{RM} | 7.0 | - | ns |
| Typical stored charge | | | Q_{rr} | 160 | - | Α |
| Typical forward recovery time | $I_F = 10 \text{ A}, \text{ dI/dt} = 80 \text{ A/}\mu\text{s}, \\ V_{FR} = 1.1 \text{ x} \ V_{F \text{ max}}.$ | | t _{fr} | 150 | - | ns |

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|----------------|--------|---------|------|--|
| PARAMETER | SYMBOL | UH10FT | UHB10FT | UNIT | |
| Typical thermal resistance | $R_{	heta JC}$ | 2.0 | 2.0 | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|---------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AC | UH10FT-E3/4W | 1.82 | 4W | 50/tube | Tube | | |
| TO-263AB | UHB10FT-E3/4W | 1.32 | 4W | 50/tube | Tube | | |
| TO-263AB | UHB10FT-E3/8W | 1.32 | 8W | 800/reel | Tape and reel | | |



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

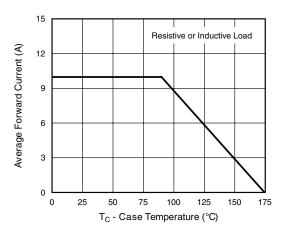


Figure 1. Maximum Forward Current Derating Curve

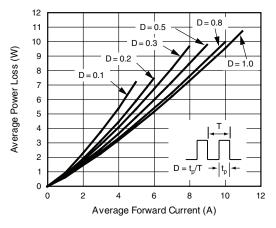


Figure 2. Forward Power Loss Characteristics

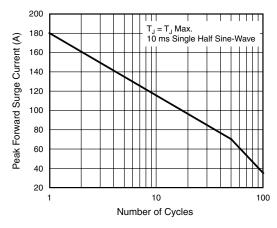


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

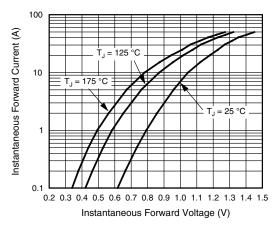


Figure 4. Typical Instantaneous Forward Characteristics

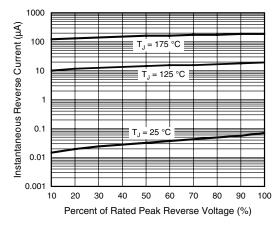


Figure 5. Typical Reverse Leakage Charactersitics

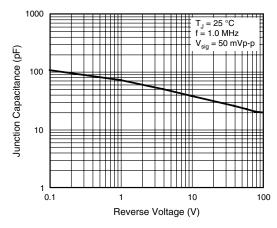


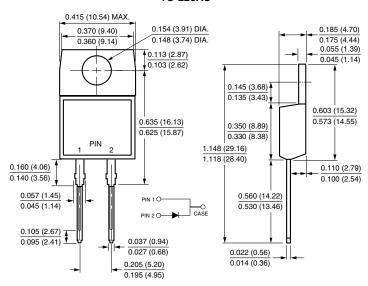
Figure 6. Typical Junction Capacitance

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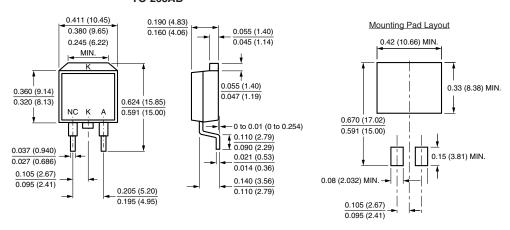


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AC



TO-263AB



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